Adopted Levels

History

Type Author Citation Literature Cutoff Date
Full Evaluation Shaofei Zhu and E. A. Mccutchan NDS 175, 1 (2021)

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 $Q(\beta^-)=6090\ CA;\ S(n)=10310\ CA;\ S(p)=1630\ CA;\ Q(\alpha)=8692\ 18$ 2021Zh22,2019Mo01 $S(2n)=19070,\ S(2p)=1480$ (theory, 2019Mo01).

 $Q(\beta^-)$, S(n) and S(p) (theory, 2019Mo01).

Q(α): Deduced from E α =8533 keV 18 (2021Zh22).

2021Zh22: ²¹⁴U was produced in ¹⁸²W(³⁶Ar,4n) with a beam at 184 MeV bombarding a ¹⁸²W target with a thickness of 300-350 μg/cm²; evaporation residues (ER) were separated in-flight by the the gas-filled recoil separator SHANS and implanted in three 16-strip position-sensitive silicon detectors (PSSDs) mounted side-by-side at the focal plane. ²¹⁴U was identified by ER-(α)-(α) time and position correlations.

²¹⁴U Levels

E(level) J^{π} $T_{1/2}$ Comments $0.0 0^{+} 0.52 ms +95-21 \%\alpha=100$

Two 214 U α -decay events with E α =8543 and E α =8522 keV were identified. Production cross-section σ = 10 pb +14-7.